NSN 5961-01-310-1019

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-310-1019 **Inclosure Material:** Plastic **Overall Length:** Between 0.330 inches and 0.350 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.220 inches and 0.240 inches Lens Transparency: Translucent all light emitting diode **Function For Which Designed:** Visible light emitting **Component Name And Quantity:** 2 light emitting diode **Mounting Method: Terminal Semiconductor Material:** Gallium phosphide 2nd light emitting diode Voltage Rating In Volts Per Characteristic: 2.2 forward voltage, dc all light emitting diode **Current Rating Per Characteristic:** 25.00 milliamperes source cutoff current preset all light emitting diode **Power Rating Per Characteristic:** 115.0 milliwatts small-signal input power, common-collector preset all light emitting diode **Color Tone Produced Per Source:** Red lens 1st light emitting diode **Luminous Intensity:** 1.8 millicandela all light emitting diode **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Special Features:** All light emitting diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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